Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in

the application:

Listing of Claims:

1. (Currently Amended) A method of backside navigation comprising:

milling a fine fiducial opening through a substrate with a charged particle

beam; and endpointing said fine fiducial opening upon delineating a trench

isolation structure to create a registration marker to register an image of said

trench isolation structure to a reference image.

2. (Currently Amended) The method according to Claim 1, further

comprising:

acquiring an said image of said delineated trench isolation structure with said

charged particle beam;

receiving a said reference image; and

registering said acquired image and said reference image.

3. (Original) The method according to Claim 2, wherein said reference

image comprises a computer aided design layout image.

4. (Currently Amended) The method according to Claim 1, wherein

endpointing said fine fiducial opening comprises: imaging a floor of said

fine fiducial opening with said charged particle beam; detecting a voltage

contrast indicating said fine fiducial opening has reached said trench

isolation structure; and stopping said milling of said fine fiducial opening

upon detecting said voltage contrast.

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- (Original) The method according to Claim 1, wherein a width of said fine fiducial opening is substantially sufficient to expose the width of said trench isolation structure.
- 6. (Original) A method of backside navigation comprising: forming a fiducial opening, wherein a portion of a trench isolation structure is delineated; acquiring an image of said delineated portion of said trench isolation structure; registering said acquired image and a reference image; and

generating position control information as a function of said registered acquired image and said reference image.

- 7. (Original) The method according to Claim 6, wherein said reference image comprises a computer aided design layout image.
- 8. (Original) The method according to Claim 6, wherein forming said fiducial opening comprises: forming a coarse fiducial opening, wherein a static device region is delineated; depositing an oxide layer in said coarse fiducial opening; and forming a fine fiducial opening in said coarse fiducial opening, wherein said portion of said trench isolation structure is delineated.
- 9. (Original) The method according to Claim 8, wherein forming said fiducial opening further comprises: imaging a boundary of said well region to detect a doping deviation in said well region indicative of a presence of said trench isolation structure; and milling said fine fiducial opening substantially at said detected doping deviation.
- 10. (Original) The method according to Claim 8, wherein forming said fiducial opening further comprises: thinning a substrate prior to forming said fiducial opening; and imaging said substrate to detect said static device region.

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- 11. (Original) The method according to Claim 6, further comprising: making a fiducial marking proximate said fiducial opening; and maintaining said registration of said acquired image and said reference image as a function of said fiducial marking.
- 12. (Original) The method according to Claim 6, wherein registering said acquired image and said reference image comprises: generating a cross correlation image as a function of said acquired image and said reference image; oversampling said cross correlation image; determining an offset of said oversampled cross correlation image; and aligning said reference image and said acquired image according to said offset.
- 13. (Original) The method according to Claim 12, wherein registering said acquired image and said reference image comprises: preprocessing said acquired image, wherein preprocessing comprises one or more processes consisting of rotation adjustment, magnification adjustment, intensity adjustment and filtering.
- 14. (Original) The method according to Claim 12, further comprising: forming a plurality of fiducial openings, wherein each fiducial opening delineates a separate portion of a trench isolation structure within a field of view; acquiring an image of each said delineated portion of said trench isolation structure; registering said image of each delineated portion of said trench isolation structure to a corresponding trench isolation structure in a portion of a trench mask corresponding to said field of view; and generating position control information as a function of said registered acquired images and said portion of said trench mask.
- 15. (Original) A method of forming a backside marker in an integrated circuit comprising: forming a coarse fiducial opening; forming a fine fiducial

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- opening in said coarse fiducial opening, wherein said fine fiducial opening delineates a portion of a trench isolation structure.
- (Original) The method according to Claim 15, wherein said coarse fiducial opening delineates a static device region.
- 17. (Original) The method according to Claim 16, wherein said static device region comprises a well region.
- 18. (Original) The method according to Claim 15, wherein a focused ion beam milling process is utilized to form said fine fiducial opening.
- 19. (Original) The method according to Claim 18, wherein forming said fine fiducial opening comprises: milling at a first focused ion beam current; milling at a second focused ion beam current as said fine fiducial opening approaches said trench isolation structure, wherein said second focused beam current is less than said first focused ion beam current; imaging said fine fiducial opening at said second focused ion beam current to detect a first voltage contrast indicative of said fine fiducial opening reaching said trench isolation structure; and stopping said milling upon detection of said first voltage contrast.
- 20. (Original) The method according to Claim 15, wherein forming said coarse fiducial opening comprises: imaging said integrated circuit to detect a position of a static device region; milling at said first focused ion beam current; milling at said second focused ion beam as said coarse fiducial opening approaches said static device region; imaging said coarse fiducial opening at said second focused ion beam current to detect a second voltage contrast indicative of said coarse fiducial opening reaching said static device region; and stopping said milling upon detection of said second voltage contrast.

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21. (Original) The method according to Claim 15, further comprising forming an initial opening, wherein said coarse fiducial opening will be formed in said initial opening.

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